NSN 5961-01-494-8632

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Inclosure Material:
Glass
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
30.0 collector to emitter voltage, dc and 65.0 collector to base voltage, dc and 3.5 emitter to base voltage, dc
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0